Key Features

- 1.5 Ohm Input Impedance
- 0.5 dB Noise Figure
- 30.0 dBm Max P_{IN}
- 24.0 dBm Output IP₃
- 28.0 dB Gain
- 8.0 dBm P_{1dB}
- 1.22:1 Output VSWR
- Unconditional Stable, k>1
- Single Power Supply
- None Magnetic

Product Description

1.5T Frequency of 63 - 64 MHz WMA1T5AE integrates WanTcom proprietary noise amplifier technologies, frequency micro electronic techniques, and high reliability designs to realize optimum low noise figure, wideband, and high performances together. With single +10.0V DC operation, the amplifier has 1.5 Ohm input impedance and unconditional stable condition. The amplifier has 0.40" x 0.25" x 0.08" surface mount package.

Applications

- Magnetic Resonance Imaging
- RF Measurement
- Medical
- Current Sensor



Specifications

Summary of the key electrical specifications at room temperature, tested in the WanTcom fixture, 8000022

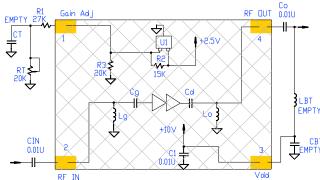
Index	Testing Item	Symbol	Test Constraints	Min	Nom	Max	Unit
1	Gain	S ₂₁	63.8 MHz, Factory test condition		28.0		dB
2	Gain Variation	ΔG	63.8 +/- 1 MHz		+/-0.03	+/- 0.05	dB
3	Input Impedance	RE [Zin]	63.8 MHz		1.5	2.0	Ohm
		IM [Zin]	63.8 MHz, with test fixture 8000022	-6.0	-3.0	0	Ohm
4	Output VSWR, 50 Ohm Impedance	SWR ₂	63.8 MHz			1.22:1	Ratio
5	Reverse Isolation	S ₁₂	63.8 MHz	60	70		dB
6	Noise Figure	NF	63.8 MHz, with 6 dB precision pad		0.47	0.60	dB
7	Output Power 1dB Compression Point	P _{1dB}	63.8 MHz	7	9		dBm
8	Output-Third-Order Interception point	IP ₃	Two-Tone, P _{out} = 0 dBm each, 1 MHz separation	20	24		dBm
9	Current Consumption	I _{dd}	V _{dd} = +10.0 V, Factory test condition		14		mA
10	Power Supply Operating Voltage	V_{dd}		+7	+10	+13	V
11	Thermal Resistance	R _{th,c}	Junction to case			220	°C/W
12	Operating Temperature	T _o		+10		+60	°C
13	Maximum RF Input Power	P _{IN, MAX}	DC - 6.0 GHz, 10% Duty Cycle, 50 Ohm Zs			30	dBm
14	Saturate Recover Time	t _{sr}	10% to 90% from 30 dBm Pin		8	10	uS
15	ESD Protection, None Contact	V _{ESDN}	Output Ports			16	kV
16	ESD Protection, Direct Contact	V _{ESD}	Output Ports			6	kV

Absolute Maximum Ratings

Parameters	Units	Ratings	
DC Power Supply Voltage	V	13.0	
Drain Current	mA	30	
Total Power Dissipation	mW	350	
RF Input Power, 10% Duty Cycle	dBm	30	
Channel Temperature	°C	150	
Storage Temperature	°C	-65 ~ 150	
Operating Temperature	°C	0 ~ +70	
Thermal Resistance ¹	°C/W	215	

Operation of this device beyond any one of these parameters may cause permanent damage

Functional Block Diagram

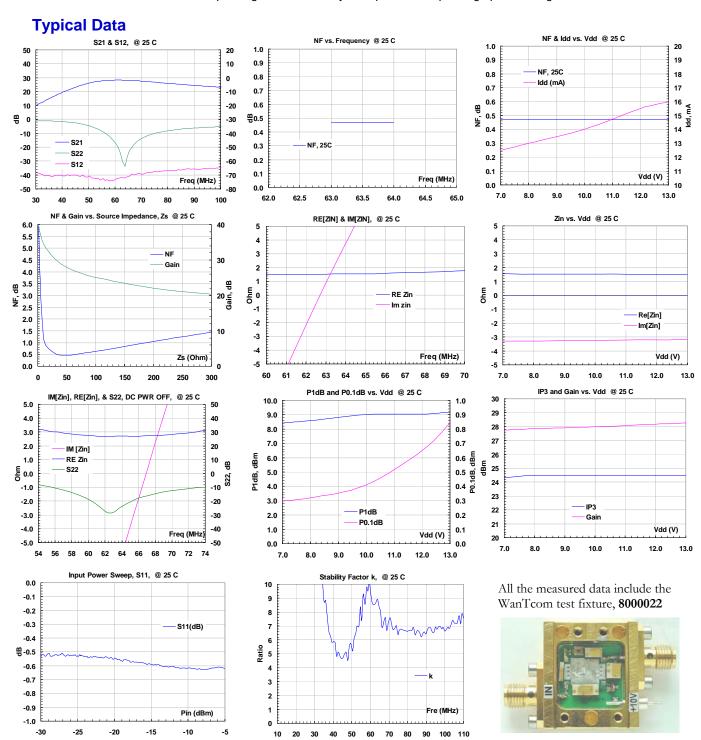


¹ The last stage transistor dominates the heat dissipation. The drain bias voltage is +6V and the drain current is 10.0 mA. The total power dissipation of the last stage transistor is thus 60 mW. The junction temperature arise $0.06 \times 215 = 13$ ($^{\circ}$ C).

Ordering Information

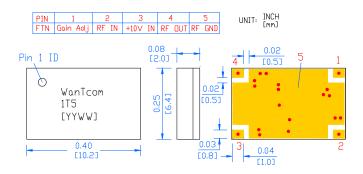
Model Number WMA1T5AE

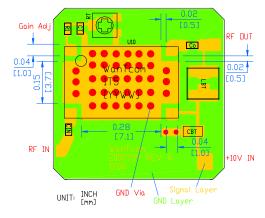
Waffle shell or tube is used for the packing. Contact factory for tape and reel packing option for higher volume order.



Outline

Foot Print/Mounting Layout





Application Notes:

A. Motherboard Layout

The recommended motherboard layout is shown in diagram of **Foot Print/Mounting Layout**. Sufficient numbers of ground vias on center ground pad are essential for the RF grounding. The width of the 50-Ohm microstrip lines at the input and output RF ports may be different for different property of the substrate. The ground plane on the backside of the substrate is needed to connect the center ground pad through the vias. The ground plane is also essential for the 50-Ohm microstrip line launches at the input and output ports.

The +10V DC voltage is applied at Pin 3 or at the output Pin 4, which requires LBT inductor of 2.2 uH. DC block capacitors, CIN and Co of 0.01 uF, are required at input and output RF ports.

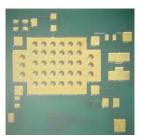


Fig. 1 Example of the motherboard

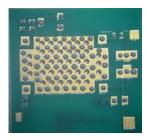


Fig. 2 Dispensed solder paste



Fig. 3 Assembled part

B. Assembly

The regular low temperature and none clean solder paste such as SN63 is recommended. The high temperature solder has been used internally for the WHM series amplifier assembly. The melting temperature point of the high temperature solder is around 217 ~ 220 °C. Thus, melting temperature of the solder paste should be below 217 °C for assembling the amplifier on the test board to reduce the possible damage. The temperature melting point of the SN63 solder paste is around 183 °C and is suitable for the assembly purpose.

The SN63 solder paste can be dispensed by a needle manually or driven by a compressed air. **Figure 2** shows the example of the dispensed solder paste pattern. Each solder paste dot is in the diameter of $0.005^{\circ} \sim 0.010^{\circ}$ ($0.125 \sim 0.250$ mm).

For volume assembly, a stencil with 0.006" (0.15 mm) is recommended to print the solder paste on the circuit board.

For more detail assembly process, refer to AN-109 at www.wantcominc.com website.